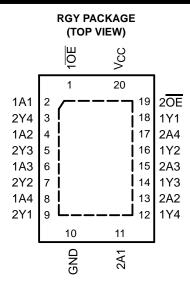
SCES433 - MARCH 2003

- Optimized for 1.8-V Operation and is 3.6-V I/O Tolerant to Support Mixed-Mode Signal Operation
- I<sub>off</sub> Supports Partial-Power-Down Mode Operation
- Sub 1-V Operable
- Max t<sub>pd</sub> of 1.9 ns at 1.8 V
- Low Power Consumption, 20-μA Max I<sub>CC</sub>
- ±8-mA Output Drive at 1.8 V
- Bus Hold on Data Inputs Eliminates the Need for External Pullup/Pulldown Resistors
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 2000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)



### description/ordering information

This octal buffer/driver is operational at 0.8-V to 2.7-V  $V_{CC}$ , but is designed specifically for 1.65-V to 1.95-V  $V_{CC}$  operation.

The SN74AUCH244 is organized as two 4-bit line drivers with separate output-enable  $(\overline{OE})$  inputs. When  $\overline{OE}$  is low, the device passes data from the A inputs to the Y outputs. When  $\overline{OE}$  is high, the outputs are in the high-impedance state.

To ensure the high-impedance state during power up or power down,  $\overline{OE}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

Active bus-hold circuitry holds unused or undriven inputs at a valid logic state. Use of pullup or pulldown resistors with the bus-hold circuitry is not recommended.

This device is fully specified for partial-power-down applications using I<sub>off</sub>. The I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

#### ORDERING INFORMATION

| TA            | PACKAGE <sup>†</sup> |               | ORDERABLE<br>PART NUMBER | TOP-SIDE<br>MARKING |
|---------------|----------------------|---------------|--------------------------|---------------------|
| –40°C to 85°C | QFN – RGY            | Tape and reel | SN74AUCH244RGYR          | MT244               |

<sup>†</sup>Package drawings, standard packing quantities, thermal data, symbolization, and PCB design guidelines are available at www.ti.com/sc/package.



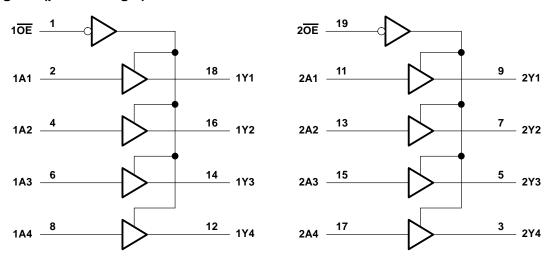
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# FUNCTION TABLE (each 4-bit buffer/driver)

| INP | JTS | OUTPUT |
|-----|-----|--------|
| ŌĒ  | Α   | Y      |
| L   | Н   | Н      |
| L   | L   | L      |
| Н   | Χ   | Z      |

### logic diagram (positive logic)



## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

| Supply voltage range, V <sub>CC</sub>  |                            |
|--|----------------------------|
| Voltage range applied to any output in the high-impedance or power-off state, V <sub>O</sub> |                            |
| (see Note 1)   | –0.5 V to 3.6 V            |
| Output voltage range, V <sub>O</sub> (see Note 1)  | –0.5 V to $V_{CC}$ + 0.5 V |
| Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0)                                    | –50 mA                     |
| Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0)                                   | –50 mA                     |
| Continuous output current, I <sub>O</sub>  | ±20 mA                     |
| Continuous current through V <sub>CC</sub> or GND  | ±100 mA                    |
| Package thermal impedance, $\theta_{JA}$ (see Note 2):                                       | 37°C/W                     |
| Storage temperature range, T <sub>stg</sub>  | –65°C to 150°C             |

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input negative-voltage and output voltage ratings may be exceeded if the input and output current ratings are observed.

2. The package thermal impedance is calculated in accordance with JESD 51-5.



### recommended operating conditions (see Note 3)

|          |                                    |   | MIN                    | MAX                  | UNIT |
|----------|------------------------------------|---|------------------------|----------------------|------|
| VCC      | Supply voltage                     |   | 0.8                    | 2.7                  | V    |
|          |                                    | $V_{CC} = 0.8 \text{ V}$                    | Vcc                    |                      |      |
| $V_{IH}$ | High-level input voltage           | $V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$ | 0.65 × V <sub>CC</sub> |                      | V    |
|          |                                    | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$  | 1.7                    |                      |      |
|          |                                    | $V_{CC} = 0.8 \text{ V}$                    |                        | 0                    |      |
| $V_{IL}$ | Low-level input voltage            | $V_{CC} = 1.1 \text{ V to } 1.95 \text{ V}$ |                        | $0.35 \times V_{CC}$ | V    |
|          |                                    | $V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$  |                        | 0.7                  |      |
| ۷Į       | Input voltage                      |   | 0                      | 3.6                  | V    |
| \/-      | Output valtage                     | Active state                                | 0                      | VCC                  | V    |
| ۷O       | O Output voltage                   | 3-state                                     | 0                      | 3.6                  | l v  |
|          |                                    | V <sub>CC</sub> = 0.8 V                     |                        | -0.7                 |      |
|          |                                    | V <sub>CC</sub> = 1.1 V                     |                        | -3                   |      |
| loH      | High-level output current          | V <sub>CC</sub> = 1.4 V                     |                        | <b>-</b> 5           | mA   |
|          |                                    | V <sub>CC</sub> = 1.65 V                    |                        | -8                   |      |
|          |                                    | V <sub>CC</sub> = 2.3 V                     |                        | -9                   |      |
|          |                                    | V <sub>CC</sub> = 0.8 V                     |                        | 0.7                  |      |
|          |                                    | V <sub>CC</sub> = 1.1 V                     |                        | 3                    |      |
| loL      | Low-level output current           | V <sub>CC</sub> = 1.4 V                     |                        | 5                    | mA   |
|          |                                    | V <sub>CC</sub> = 1.65 V                    | 8                      |                      | ]    |
|          |                                    | V <sub>CC</sub> = 2.3 V                     |                        | 9                    |      |
| Δt/Δν    | Input transition rise or fall rate | -   |                        | 20                   | ns/V |
| TA       | Operating free-air temperature     |   | -40                    | 85                   | °C   |

NOTE 3: All unused control inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



## SN74AUCH244 OCTAL BUFFER/DRIVER WITH 3-STATE OUTPUTS

SCES433 - MARCH 2003

# electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

| PARAMETER                      | TEST CONDITIONS                         | VCC            | MIN                 | TYP† | MAX  | UNIT |  |  |  |
|--------------------------------|---|----------------|---------------------|------|------|------|--|--|--|
|                                | I <sub>OH</sub> = -100 μA               | 0.8 V to 2.7 V | V <sub>CC</sub> -0. | 1    |      |      |  |  |  |
|                                | $I_{OH} = -0.7 \text{ mA}$              | 0.8 V          |                     | 0.55 |      |      |  |  |  |
| Voн                            | I <sub>OH</sub> = -3 mA                 | 1.1 V          | 0.8                 |      |      | ٧    |  |  |  |
| VOH                            | I <sub>OH</sub> = -5 mA                 | 1.4 V          | 1                   |      |      | V    |  |  |  |
|                                | I <sub>OH</sub> = -8 mA                 | 1.65 V         | 1.2                 |      |      |      |  |  |  |
|                                | I <sub>OH</sub> = -9 mA                 | 2.3 V          | 1.8                 |      |      |      |  |  |  |
|                                | I <sub>OL</sub> = 100 μA                | 0.8 V to 2.7 V |                     |      | 0.2  |      |  |  |  |
|                                | $I_{OL} = 0.7 \text{ mA}$               | 0.8 V          |                     | 0.25 |      |      |  |  |  |
| l va                           | $I_{OL} = 3 \text{ mA}$                 | 1.1 V          |                     |      | 0.3  | V    |  |  |  |
| VOL                            | I <sub>OL</sub> = 5 mA                  | 1.4 V          |                     |      | 0.4  | V    |  |  |  |
|                                | I <sub>OL</sub> = 8 mA                  | 1.65 V         |                     |      | 0.45 |      |  |  |  |
|                                | I <sub>OL</sub> = 9 mA                  | 2.3 V          |                     |      | 0.6  |      |  |  |  |
| I <sub>I</sub> A and OE inputs | $V_I = V_{CC}$ or GND                   | 0 to 2.7 V     |                     |      | ±5   | μΑ   |  |  |  |
|                                | V <sub>I</sub> = 0.35 V                 | 1.1 V          | 10                  |      |      |      |  |  |  |
| lat                            | V <sub>I</sub> = 0.47 V                 | 1.4 V          | 15                  |      |      | μΑ   |  |  |  |
| I <sub>BHL</sub> ‡             | V <sub>I</sub> = 0.57 V                 | 1.65 V         | 20                  |      |      |      |  |  |  |
|                                | V <sub>I</sub> = 0.7 V                  | 2.3 V          | 40                  |      |      |      |  |  |  |
|                                | V <sub>I</sub> = 0.8 V                  | 1.1 V          | -10                 |      |      | μΑ   |  |  |  |
| J8                             | V <sub>I</sub> = 0.9 V                  | 1.4 V          | -15                 |      |      |      |  |  |  |
| I <sub>BHH</sub> §             | V <sub>I</sub> = 1.07 V                 | 1.65 V         | -20                 |      |      |      |  |  |  |
|                                | V <sub>I</sub> = 1.7 V                  | 2.3 V          | -40                 |      |      |      |  |  |  |
|                                |   | 1.3 V          | 75                  |      |      |      |  |  |  |
| <br> ¶                         | \\\ - 0 to \\\ - 0                      | 1.6 V          | 125                 |      |      |      |  |  |  |
| IBHLO¶                         | $V_I = 0$ to $V_{CC}$                   | 1.95 V         | 175                 |      |      | μΑ   |  |  |  |
|                                |   | 2.7 V          | 275                 |      |      |      |  |  |  |
|                                |   | 1.3 V          | <del>-</del> 75     |      |      |      |  |  |  |
| #                              | \\. 0 to \/ = -                         | 1.6 V          | -125                |      |      | ^    |  |  |  |
| <sup>І</sup> внно <sup>#</sup> | VI = 0 to $VCC$                         | 1.95 V         | -175                |      |      | μΑ   |  |  |  |
|                                |   | 2.7 V          | -275                |      |      |      |  |  |  |
| l <sub>off</sub>               | $V_I$ or $V_O = 2.7 V$                  | 0              |                     |      | ±10  | μΑ   |  |  |  |
| loz                            | $V_O = V_{CC}$ or GND                   | 2.7 V          |                     |      | ±10  | μΑ   |  |  |  |
| Icc                            | $V_I = V_{CC}$ or GND, $I_O = 0$        | 0.8 V to 2.7 V |                     |      | 20   | μΑ   |  |  |  |
| C <sub>i</sub>                 | $V_I = V_{CC}$ or GND                   | 2.5 V          |                     | 2.5  | 3    | pF   |  |  |  |
| Co                             | V <sub>O</sub> = V <sub>CC</sub> or GND | 2.5 V          |                     | 5.5  | 6    | pF   |  |  |  |

<sup>&</sup>lt;sup>†</sup> All typical values are at  $T_A = 25$ °C.



<sup>&</sup>lt;sup>‡</sup> The bus-hold circuit can sink at least the minimum low sustaining current at V<sub>IL</sub> max. I<sub>BHL</sub> should be measured after lowering V<sub>IN</sub> to GND and then raising it to V<sub>IL</sub> max.

<sup>§</sup> The bus-hold circuit can source at least the minimum high sustaining current at V<sub>IH</sub> min. I<sub>BHH</sub> should be measured after raising V<sub>IN</sub> to V<sub>CC</sub> and then lowering it to V<sub>IH</sub> min.

 $<sup>\</sup>P$  An external driver must source at least  $I_{\mbox{\footnotesize{BHLO}}}$  to switch this node from low to high.

<sup>#</sup> An external driver must sink at least I<sub>BHHO</sub> to switch this node from high to low.

SCES433 - MARCH 2003

# switching characteristics over recommended operating free-air temperature range, $C_L$ = 15 pF (unless otherwise noted) (see Figure 1)

| PARAMETER        | FROM<br>(INPUT) | TO<br>(OUTPUT) | V <sub>CC</sub> = 0.8 V |     | : 1.2 V<br>.1 V | V <sub>CC</sub> = | : 1.5 V<br>1 V |     | ;C = 1.8<br>: 0.15 V |     | V <sub>CC</sub> = |     | UNIT |
|------------------|-----------------|----------------|-------------------------|-----|-----------------|-------------------|----------------|-----|----------------------|-----|-------------------|-----|------|
|                  | (1141 01)       | (0011 01)      | TYP                     | MIN | MAX             | MIN               | MAX            | MIN | TYP                  | MAX | MIN               | MAX |      |
| t <sub>pd</sub>  | А               | Y              | 6.5                     | 1.1 | 3.7             | 0.6               | 2.3            | 0.5 | 1.1                  | 1.9 | 0.4               | 1.5 | ns   |
| t <sub>en</sub>  | ŌĒ              | Y              | 8                       | 1.2 | 4.5             | 0.7               | 2.8            | 0.6 | 1.2                  | 2.3 | 0.5               | 1.7 | ns   |
| <sup>t</sup> dis | ŌĒ              | Υ              | 10.4                    | 1.7 | 6               | 1.1               | 4              | 1.7 | 2.4                  | 4.2 | 0.6               | 3.8 | ns   |

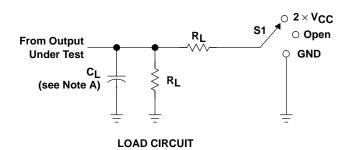
# switching characteristics over recommended operating free-air temperature range, $C_L$ = 30 pF (unless otherwise noted) (see Figure 1)

| PARAMETER        | FROM<br>(INPUT) |          |     | C = 1.8 |     | V <sub>CC</sub> = ± 0. |     | UNIT |
|------------------|-----------------|----------|-----|---------|-----|------------------------|-----|------|
|                  | (INFOT)         | (001701) | MIN | TYP     | MAX | MIN                    | MAX |      |
| <sup>t</sup> pd  | А               | Υ        | 0.8 | 1.5     | 2.5 | 0.7                    | 1.9 | ns   |
| t <sub>en</sub>  | ŌĒ              | Υ        | 0.8 | 1.7     | 3.1 | 0.7                    | 2.3 | ns   |
| t <sub>dis</sub> | ŌE              | Υ        | 1.7 | 2.4     | 4.2 | 0.5                    | 2.3 | ns   |

## operating characteristics, $T_A = 25^{\circ}C$

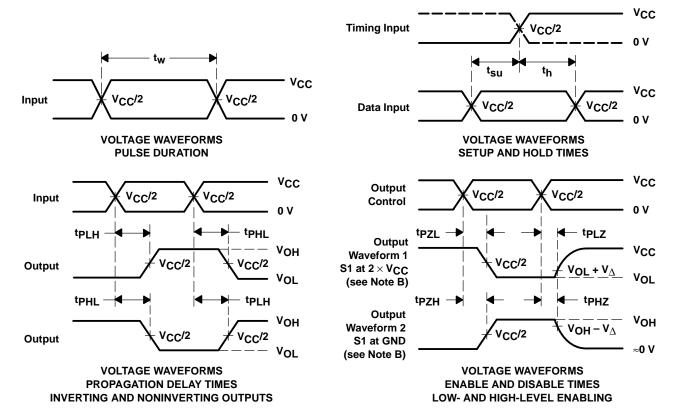
|                 | PARAMETE             | R                   | TEST<br>CONDITIONS | V <sub>CC</sub> = 0.8 V | V <sub>CC</sub> = 1.2 V<br>TYP | V <sub>CC</sub> = 1.5 V | V <sub>CC</sub> = 1.8 V<br>TYP | V <sub>CC</sub> = 2.5 V | UNIT |
|-----------------|----------------------|---------------------|--------------------|-------------------------|--------------------------------|-------------------------|--------------------------------|-------------------------|------|
|                 |                      |                     |                    | 111                     | 1115                           | 1117                    | 1115                           | 111                     |      |
| C <sub>pd</sub> | Power<br>dissipation | Outputs enabled     | f = 10 MHz         | 21                      | 21                             | 22                      | 22                             | 25                      | pF   |
| Opa             | capacitance          | Outputs<br>disabled | I = IO WIHZ        | 3                       | 3                              | 3                       | 4                              | 5                       | рг   |

### PARAMETER MEASUREMENT INFORMATION



| TEST                               | S1                |
|------------------------------------|-------------------|
| tPLH/tPHL                          | Open              |
| t <sub>PLZ</sub> /t <sub>PZL</sub> | 2×V <sub>CC</sub> |
| tPHZ/tPZH                          | GND               |

| VCC                | CL    | RL           | $oldsymbol{V}_\Delta$ |
|--------------------|-------|--------------|-----------------------|
| 0.8 V              | 15 pF | <b>2 k</b> Ω | 0.1 V                 |
| 1.2 V $\pm$ 0.1 V  | 15 pF | <b>2 k</b> Ω | 0.1 V                 |
| 1.5 V ± 0.1 V      | 15 pF | <b>2 k</b> Ω | 0.1 V                 |
| 1.8 V $\pm$ 0.15 V | 15 pF | <b>2 k</b> Ω | 0.15 V                |
| 2.5 V $\pm$ 0.2 V  | 15 pF | <b>2 k</b> Ω | 0.15 V                |
| 1.8 V $\pm$ 0.15 V | 30 pF | <b>1 k</b> Ω | 0.15 V                |
| 2.5 V $\pm$ 0.2 V  | 30 pF | 500 Ω        | 0.15 V                |



- NOTES: A. C<sub>L</sub> includes probe and jig capacitance.
  - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control.

    Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
  - C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz,  $Z_O = 50 \Omega$ , slew rate  $\geq$  1 V/ns.
  - D. The outputs are measured one at a time with one transition per measurement.
  - E. tpLz and tpHz are the same as tdis.
  - F. tpzL and tpzH are the same as ten.
  - G. tplH and tpHL are the same as tpd.
  - H. All parameters and waveforms are not applicable to all devices.

Figure 1. Load Circuit and Voltage Waveforms





### PACKAGE OPTION ADDENDUM

30-Mar-2005

### PACKAGING INFORMATION

| Orderable Device | Status <sup>(1)</sup> | Package<br>Type | Package<br>Drawing | Pins F | Package<br>Qty | Eco Plan <sup>(2)</sup> | Lead/Ball Finish | MSL Peak Temp <sup>(3)</sup> |
|------------------|-----------------------|-----------------|--------------------|--------|----------------|-------------------------|------------------|------------------------------|
| SN74AUCH244RGYR  | ACTIVE                | QFN             | RGY                | 20     | 1000           | Green (RoHS & no Sb/Br) | CU NIPDAU        | Level-2-260C-1YEAR           |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

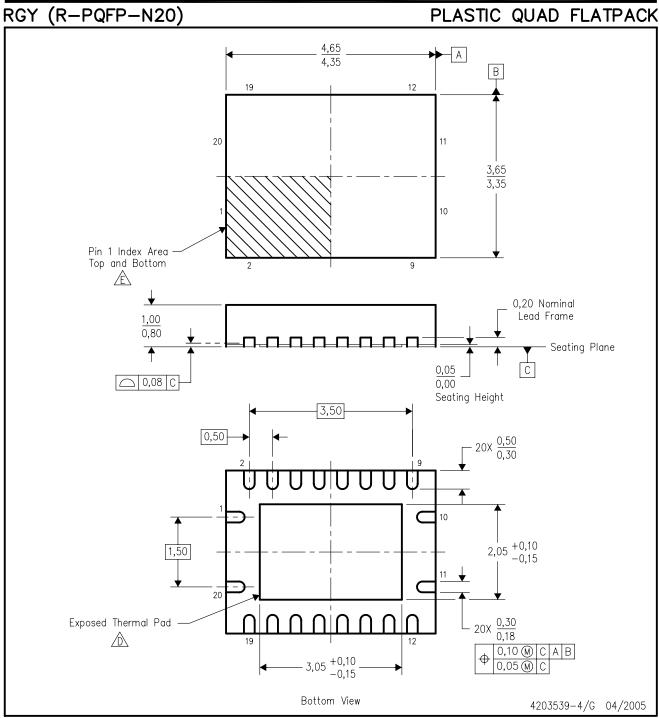
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

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(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance.
- Pin 1 identifiers are located on both top and bottom of the package and within the zone indicated. The Pin 1 identifiers are either a molded, marked, or metal feature.
- F. Package complies to JEDEC MO-241 variation BC.



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